NPN Epitaxial Planar Silicon Transistor



2SC4931

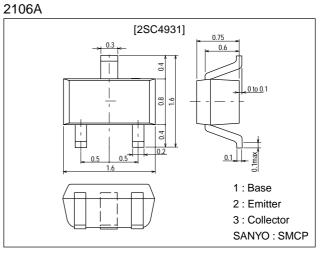
VHF to UHF Wide-Band Low-Noise Amplifier Applications

Features

- · Low noise : NF=1.2dB typ (f=1GHz).
- High gain : $|S21e|^2=13$ dB typ (f=1GHz).
- \cdot High cutoff frequency : $f_T\!=\!9.0GHz$ typ.
- Very small-sized package permitting 2SC4931applied sets to be made small and slim.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		16	V
Collector-to-Emitter Voltage	VCEO		8	V
Emitter-to-Base Voltage	VEBO		1.5	V
Collector Current	ι _C		50	mA
Collector Dissipation	PC		100	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

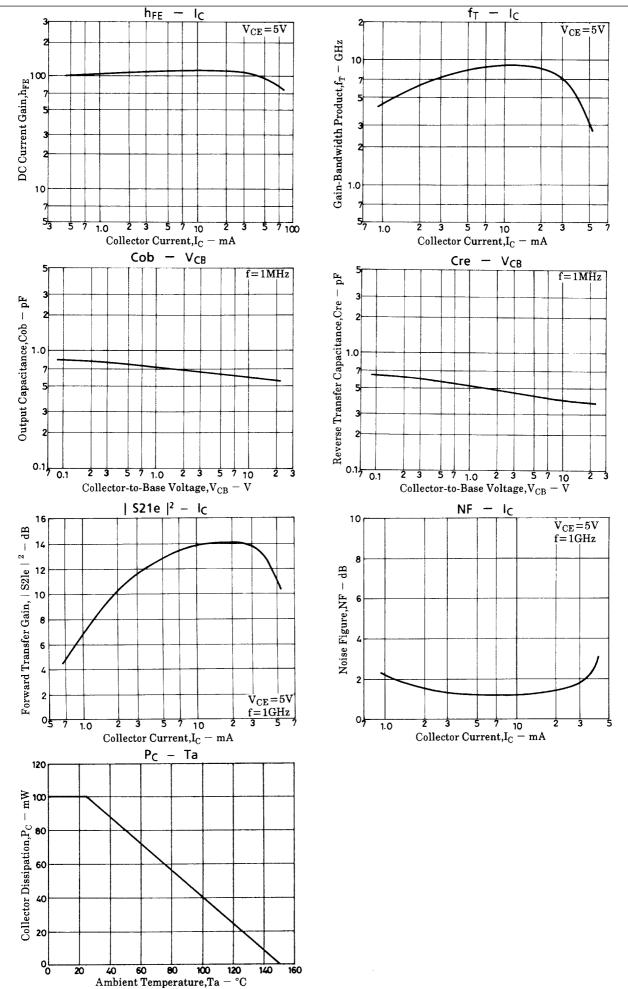
Parameter	Symbol	Conditions		Ratings		
i alameter	Gymbol	Conditions	min	typ	max 1.0 10 270* 1.2	Unit
Collector Cutoff Current	ICBO	V _{CB} =10V, I _E =0			1.0	μA
Emitter Cutoff Current	IEBO	V _{EB} =1V, I _C =0			10	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =15mA	60*		270*	
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =15mA		9.0		GHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		0.55	1.2	pF
Forward Transfer Gain	S21e ²	V _{CE} =5V, I _C =15mA, f=1GHz	10	13		dB
Noise Figure	NF	V _{CE} =5V, I _C =5mA, f=1GHz		1.2	2.5	dB

 \ast : The 2SC4931 is classified by 15mA h_{FE} as follows :

Marking	B1	B2	В3		
hFE	60 to 120	90 to 180	135 to 270		

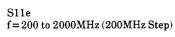
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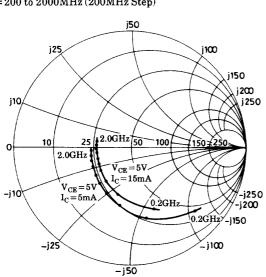
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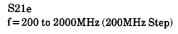


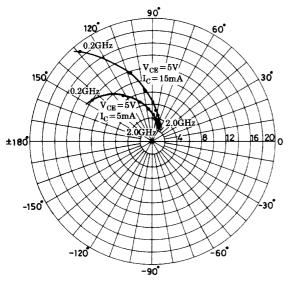
S12e

S parameter





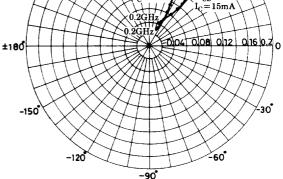




150 $V_{CE} = 5V_{I_C}$ 11 0.2GHz

f=200 to 2000MHz (200MHz Step)

120



90

2.0GH

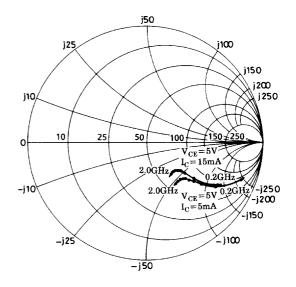
60

2.0ĜHz

ce = 5V

30

S22e f = 200 to 2000MHz (200MHz Step)



S parameter (Common emitter)

 $V_{CE}=5V, I_C=5mA, Z_O=50\Omega$

Freq (MHz)	S ₁₁	∠ s ₁₁	S ₂₁	∠ S ₂₁	S ₁₂	∠ S ₁₂	S ₂₂	∠ S ₂₂
200	0.775	-45.2	11.958	144.8	0.040	67.3	0.872	-21.4
400	0.620	-78.1	8.989	122.3	0.063	56.2	0.704	-32.1
600	0.517	-100.9	6.908	107.9	0.076	52.2	0.594	-36.7
800	0.451	-117.9	5.487	97.6	0.087	51.3	0.529	-39.2
1000	0.411	-131.5	4.553	89.8	0.097	51.9	0.491	-40.9
1200	0.385	-142.0	3.899	83.4	0.107	52.7	0.467	-42.5
1400	0.372	-152.5	3.411	77.3	0.117	53.7	0.451	-44.1
1600	0.364	-161.7	3.052	71.3	0.129	54.7	0.438	-46.2
1800	0.353	-168.5	2.740	66.7	0.139	55.4	0.435	-48.8
2000	0.349	-176.6	2.507	62.7	0.152	56.2	0.435	-51.2

$V_{CE}{=}5V\!, I_{C}{=}15mA, Z_{O}{=}50\Omega$

Freq (MHz)	S ₁₁	∠s ₁₁	S ₂₁	∠s ₂₁	S ₁₂	$\angle s_{12}$	S ₂₂	∠S ₂₂
200	0.560	-70.0	19.044	129.1	0.032	63.2	0.710	-31.1
400	0.422	-106.3	11.887	108.4	0.048	59.7	0.515	-37.2
600	0.364	-127.3	8.449	97.5	0.061	61.3	0.430	-37.9
800	0.330	-143.0	6.510	89.6	0.075	62.5	0.391	-38.8
1000	0.315	-153.4	5.285	83.6	0.089	63.5	0.371	-39.7
1200	0.306	-161.8	4.484	78.4	0.103	64.1	0.360	-41.0
1400	0.302	-170.7	3.898	73.4	0.118	64.2	0.352	-42.7
1600	0.309	-178.5	3.464	68.5	0.133	64.0	0.346	-45.1
1800	0.302	176.0	3.094	64.7	0.147	63.6	0.344	-48.0
2000	0.299	170.6	2.828	61.2	0.163	63.1	0.348	-50.8

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